

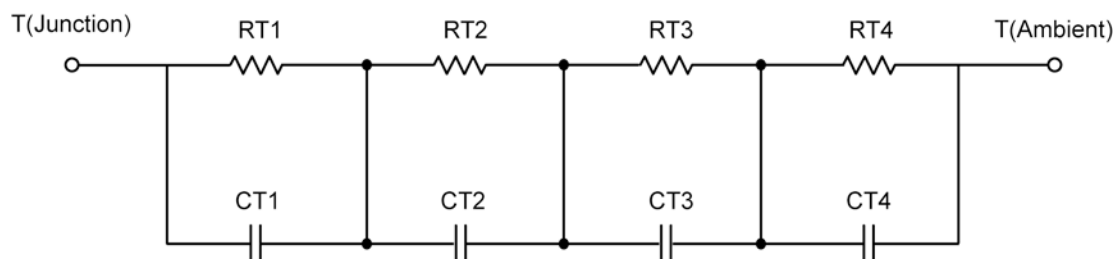
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

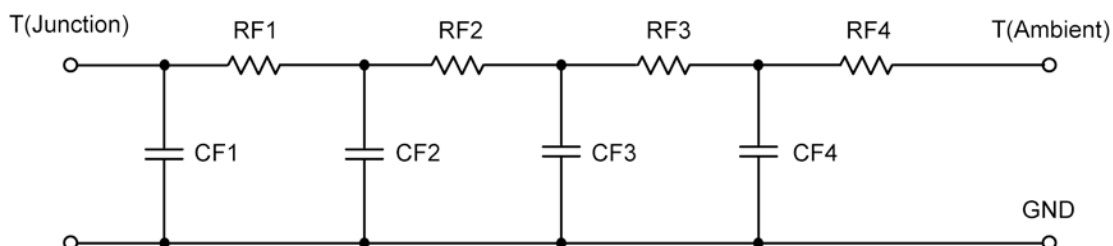
These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	4.2360	N/A	8.8222
RT2	23.1091	N/A	8.3346
RT3	10.7927	N/A	6.3964
RT4	51.8622	N/A	1.4468
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.7697 m	N/A	188.4095 m
CT2	76.4367 m	N/A	26.9507 m
CT3	30.8322 m	N/A	9.6798 m
CT4	1.2462	N/A	1.4592 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	7.0404	N/A	1.2758
RF2	30.5486	N/A	8.0257
RF3	36.0109	N/A	8.4925
RF4	16.4001	N/A	7.2060
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	2.3510 m	N/A	868.6215 u
CF2	32.3812 m	N/A	4.3125 m
CF3	928.7569 m	N/A	13.9642 m
CF4	2.7834	N/A	186.2520 m

Note: NA indicates not applicable

